

SHINDENGEN

VX-2 Series Power MOSFET

N-Channel Enhancement type

2SK2563
(F4F60VX2)

600V4A

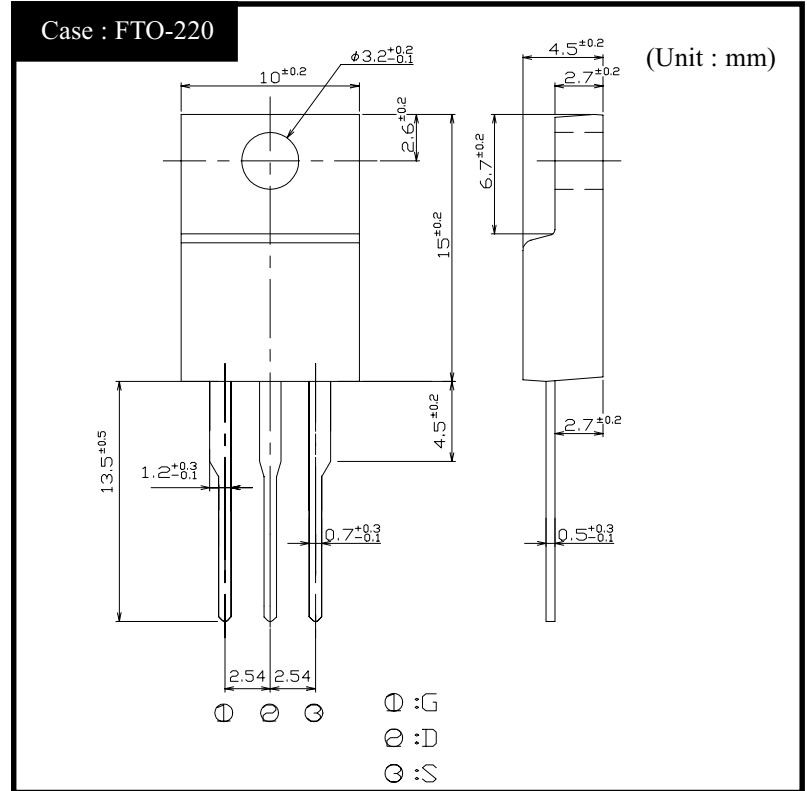
FEATURES

- Input capacitance (Ciss) is small. Especially, input capacitance at 0 bias is small.
- The static Rds(on) is small.
- The switching time is fast.
- Avalanche resistance guaranteed.

APPLICATION

- Switching power supply of AC 100-200V input
- Inverter
- Power Factor Control Circuit

OUTLINE DIMENSIONS



RATINGS

- Absolute Maximum Ratings (Tc = 25°C)

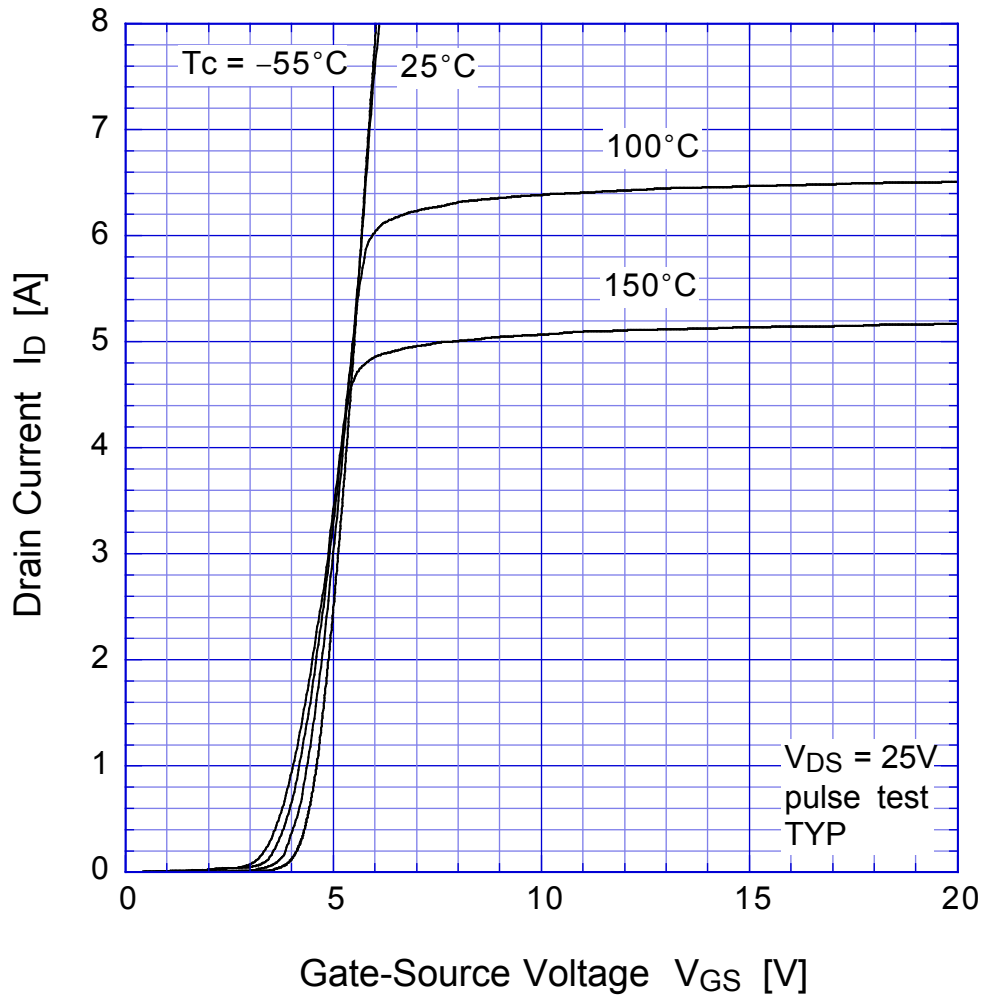
Item	Symbol	Conditions	Ratings	Unit
Storage Temperature	T _{stg}		-55~150	°C
Channel Temperature	T _{ch}		150	
Drain-Source Voltage	V _{DSS}		600	V
Gate-Source Voltage	V _{GSS}		±30	
Continuous Drain Current (DC)	I _D		4	A
Continuous Drain Current (Peak)	I _{DP}		12	
Continuous Source Current (DC)	I _S		4	
Total Power Dissipation	P _T		30	W
Single Pulse Avalanche Current	I _{AS}	T _{ch} = 25°C	4	A
Dielectric Strength	V _{dis}	Terminals to case, AC 1 minute	2	kV
Mounting Torque	TOR	(Recommended torque : 0.3N·m)	0.5	N·m

●Electrical Characteristics $T_c = 25^\circ\text{C}$

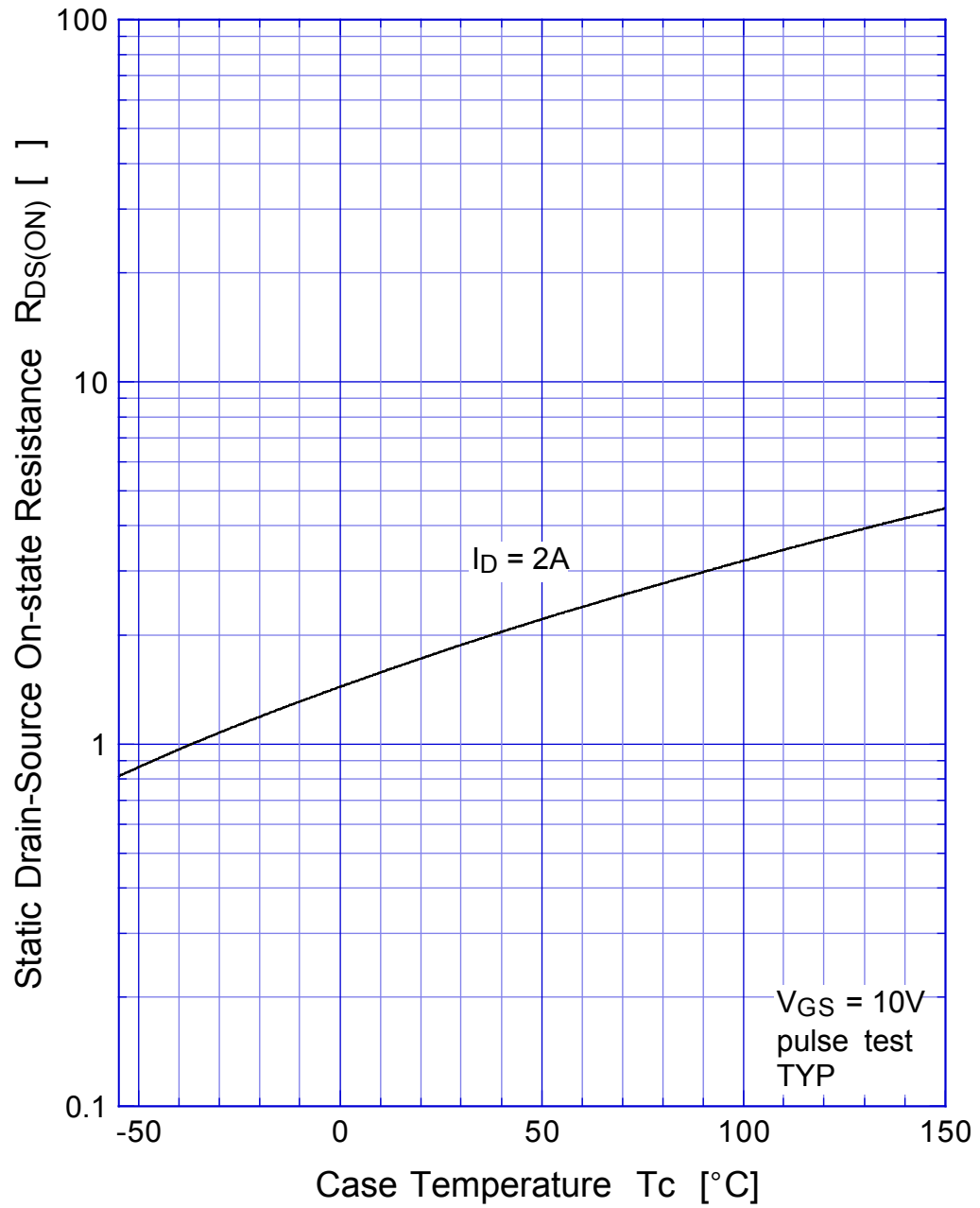
Item	Symbol	Conditions	Min.	Typ.	Max.	Unit
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$I_D = 1\text{mA}, V_{GS} = 0\text{V}$	600			V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = 600\text{V}, V_{GS} = 0\text{V}$			250	μA
Gate-Source Leakage Current	I_{GSS}	$V_{GS} = \pm 30\text{V}, V_{DS} = 0\text{V}$			± 0.1	
Forward Transconductance	g_{fs}	$I_D = 2\text{A}, V_{DS} = 10\text{V}$	1.5	3.8		S
Static Drain-Source On-state Resistance	$R_{DS(ON)}$	$I_D = 2\text{A}, V_{GS} = 10\text{V}$		1.8	2.2	Ω
Gate Threshold Voltage	V_{TH}	$I_D = 1\text{mA}, V_{DS} = 10\text{V}$	2.5	3.0	3.5	V
Source-Drain Diode Forwade Voltage	V_{SD}	$I_S = 2\text{A}, V_{GS} = 0\text{V}$			1.5	
Thermal Resistance	θ_{jc}	junction to case			4.16	$^\circ\text{C}/\text{W}$
Total Gate Charge	Q_g	$V_{DD} = 400\text{V}, V_{GS} = 10\text{V}, I_D = 4\text{A}$		21		nC
Input Capacitance	C_{iss}	$V_{DS} = 10\text{V}, V_{GS} = 0\text{V}, f = 1\text{MHz}$		540		pF
Reverse Transfer Capacitance	C_{rss}			40		
Output Capacitance	C_{oss}			120		
Turn-On Time	t_{on}	$I_D = 2\text{A}, R_L = 75\Omega, V_{GS} = 10\text{V}$		28	40	ns
Turn-Off Time	t_{off}			110	160	

2SK2563

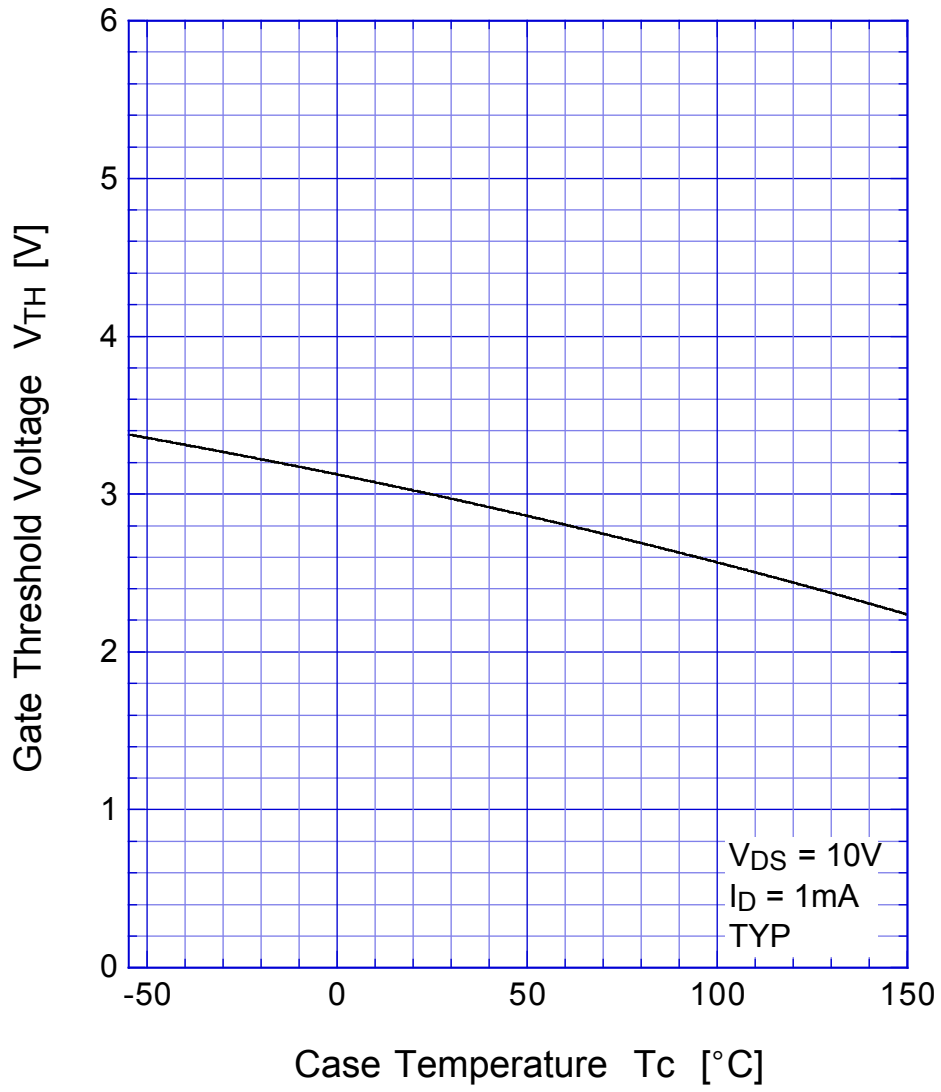
Transfer Characteristics



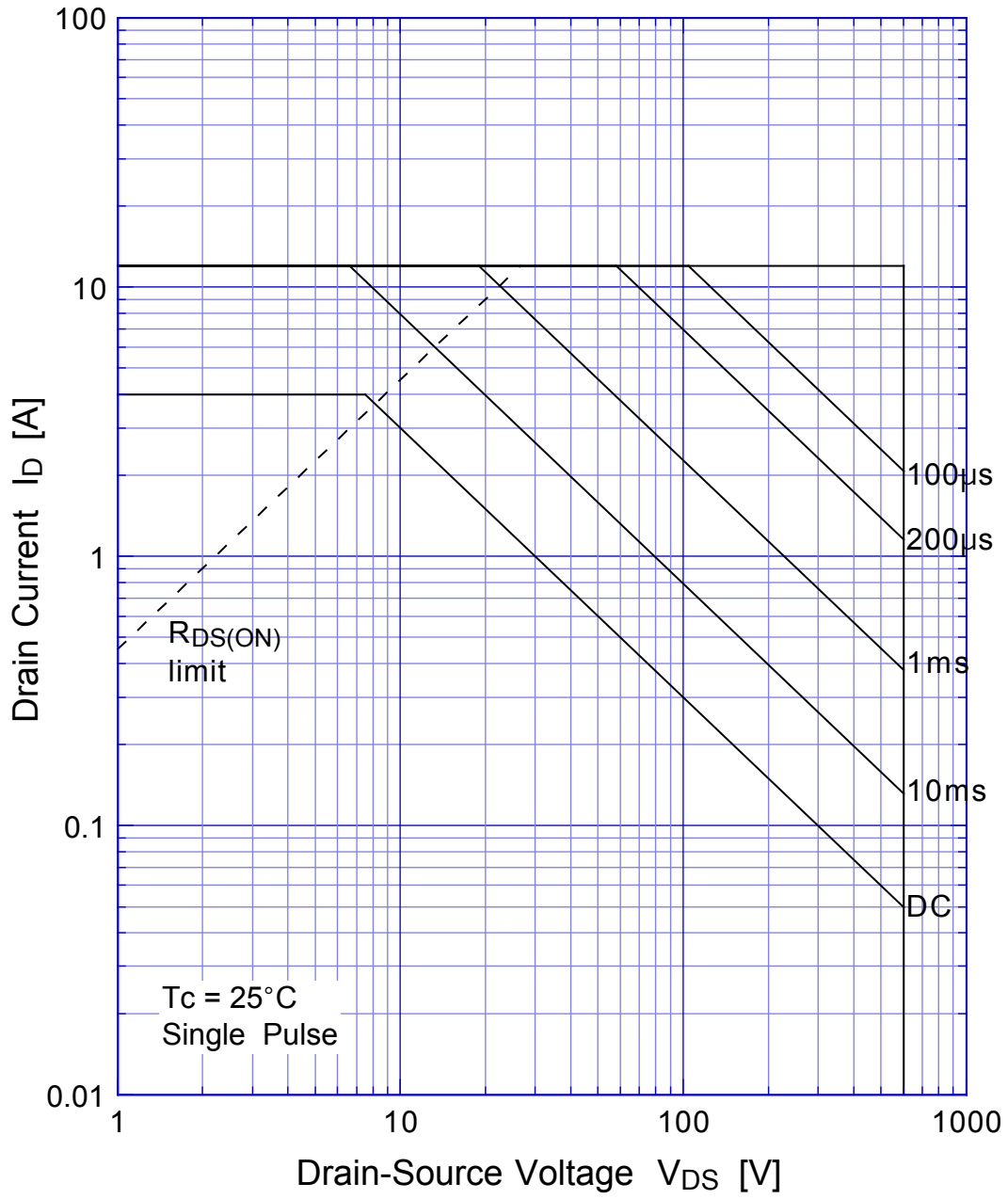
2SK2563 Static Drain-Source On-state Resistance



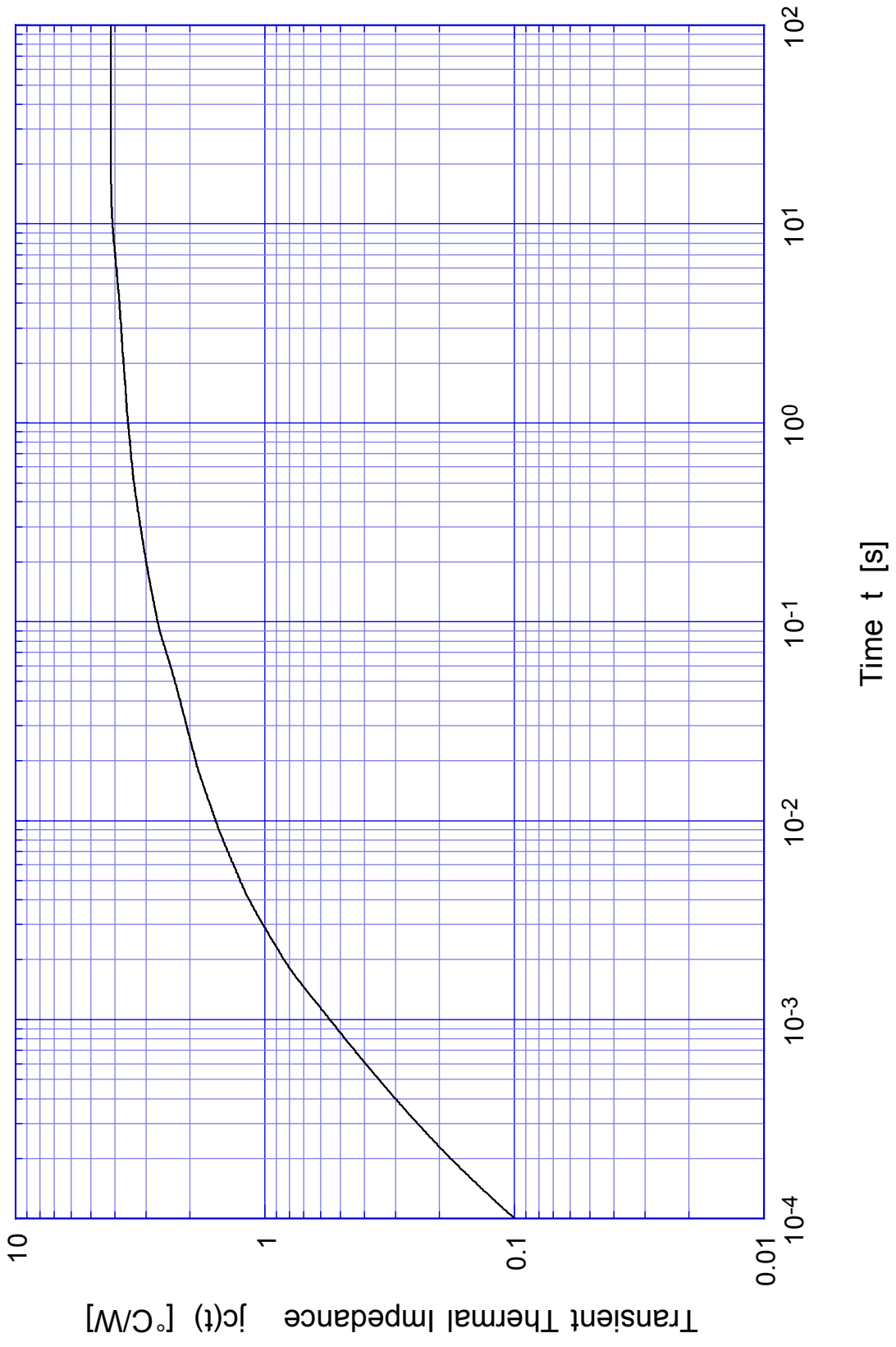
2SK2563 Gate Threshold Voltage



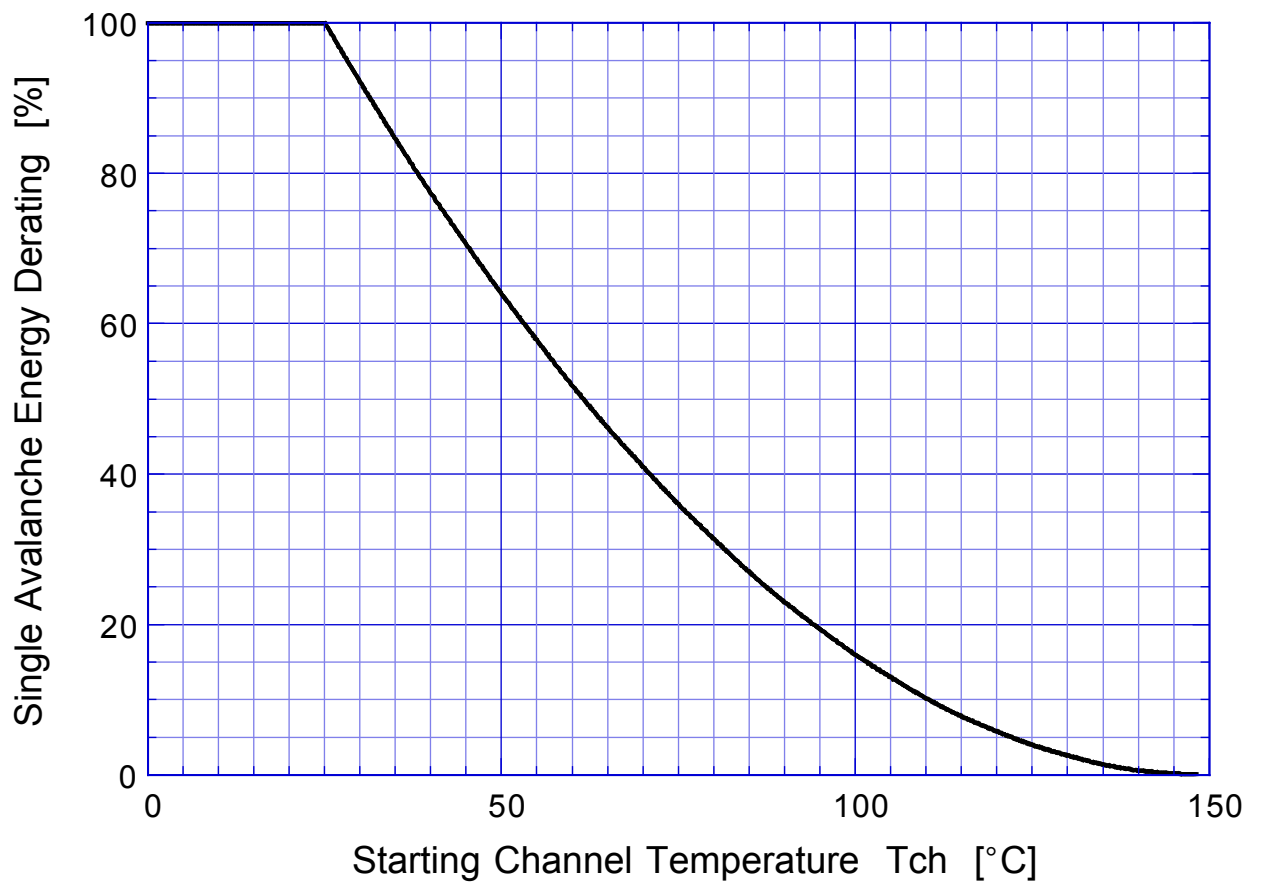
2SK2563 Safe Operating Area



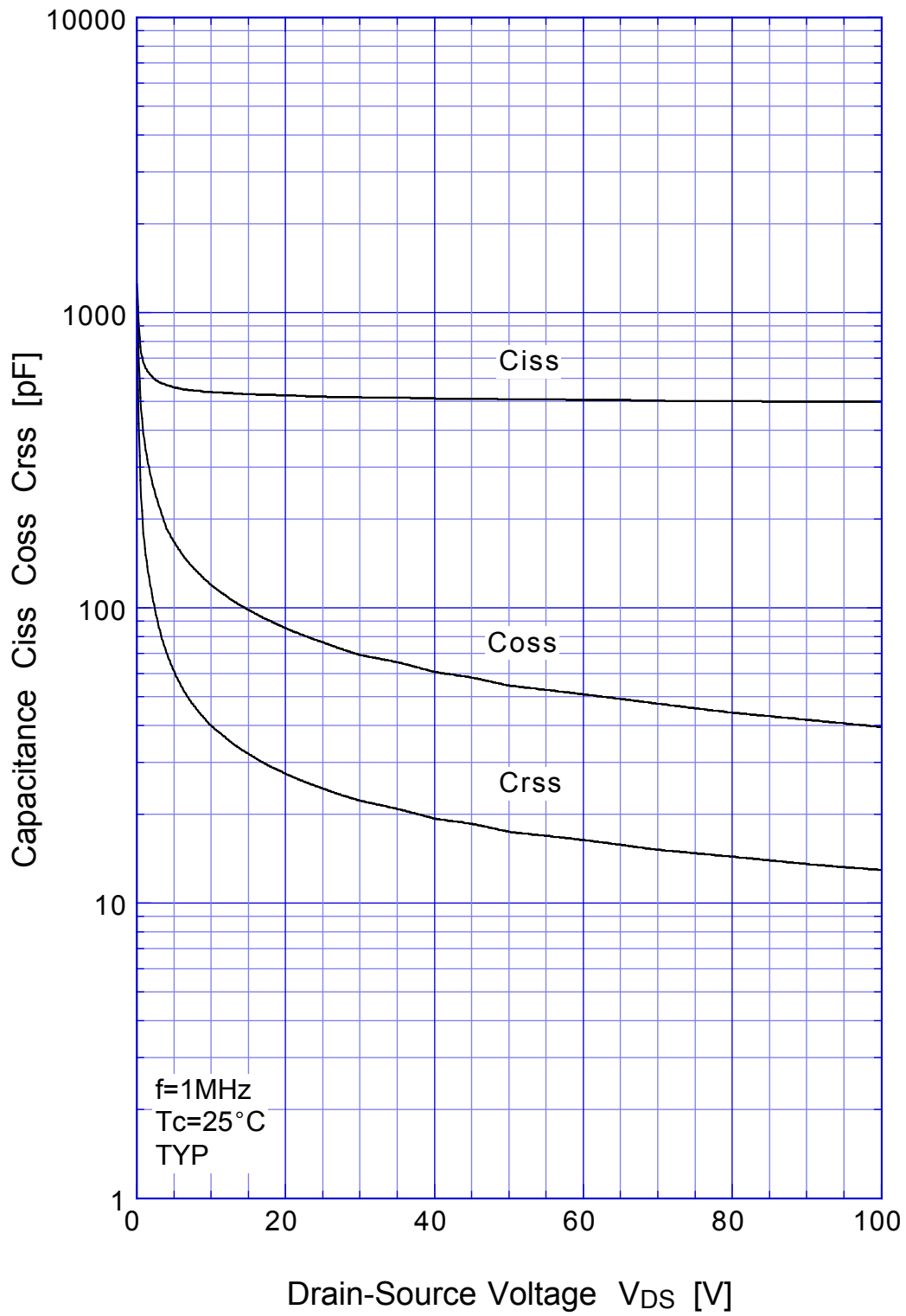
2SK2563 Transient Thermal Impedance



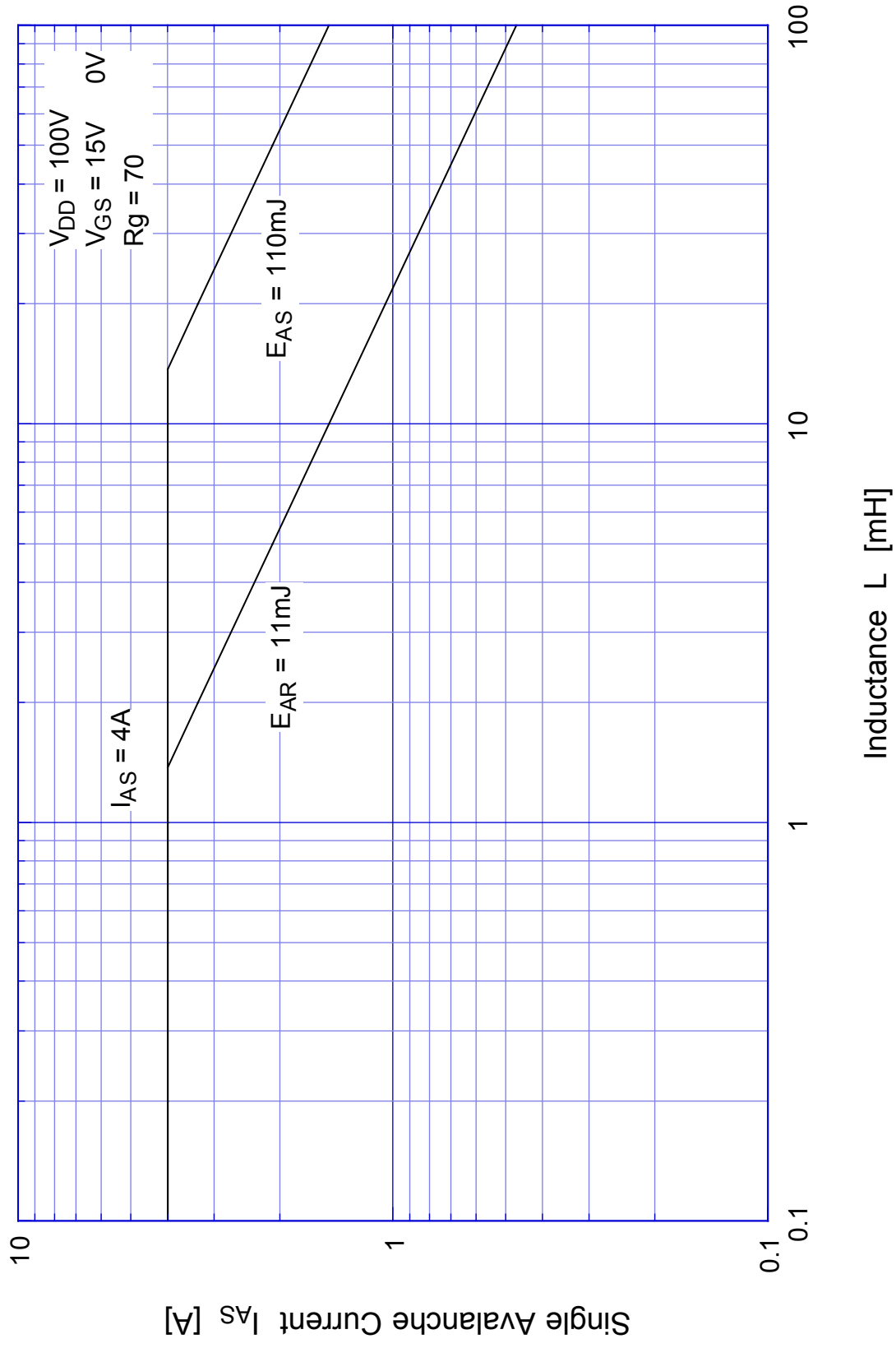
2SK2563 Single Avalanche Energy Derating



2SK2563 Capacitance

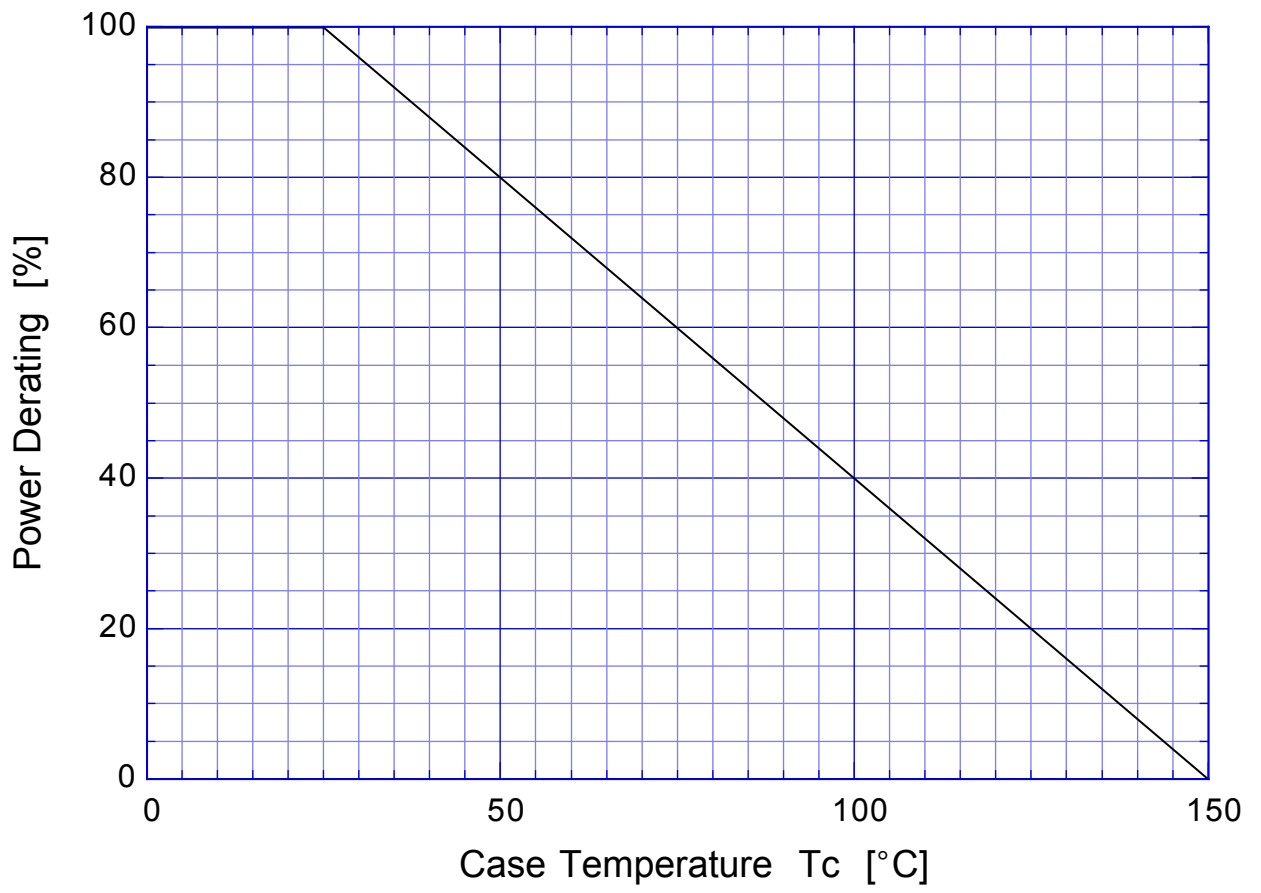


2SK2563 Single Avalanche Current - Inductive Load



2SK2563

Power Derating



2SK2563 Gate Charge Characteristics

